```
Set boxes
boxLeft = 0.45;
boxRight = 0.55;
boxBottom = 0.7;
boxTop = 0.3;
Btype = 's'; % specular boxes
% Btype = 'd'; % diffusive boxes
dx = regL / nx;
dy = regW / ny;
condHigh = 1;
condLow = 10e-2;
cMap = zeros(nx,ny);
for i = 1:nx
    for j = 1:ny
        if ((i>=boxLeft*nx) && (i<=boxRight*nx) && (((j>=boxBottom*ny)
 && (j<=ny)) | ((j<=boxTop*ny) && (j>=0))))
            cMap(i,j) = condLow;
        else
            cMap(i,j) = condHigh;
        end
    end
end
G = sparse(nx*ny);
F = zeros(nx*ny,1);
for i = 1:nx
    for j = 1:ny
        n = j + (i-1)*ny; % node mapping
        if i == 1 % left side = V_0
            G(n,n) = 1;
            F(n) = V 0;
        elseif i == nx % right side = 0V
            G(n,n) = 1;
            F(n) = 0;
        elseif j == ny % top side = insulated
```

```
n(x-1,y), n(x+1,y), n(x,y-1)
          nxm = j + (i-2)*ny;
           nxp = j + i*ny;
           nym = (j-1) + (i-1)*ny;
          rxm = (cMap(i,j) + cMap(i-1,j))/2.0;
           rxp = (cMap(i,j) + cMap(i+1,j))/2.0;
           rym = (cMap(i,j) + cMap(i,j-1))/2.0;
           G(n,n) = -(rxm + rxp + rym);
           G(n,nxm) = rxm;
           G(n,nxp) = rxp;
           G(n,nym) = rym;
       elseif j == 1 % bottom side = insulated
           % only three resistors:
           n(x-1,y), n(x+1,y), n(x,y+1)
           nxm = j + (i-2)*ny;
           nxp = j + i*ny;
           nyp = (j+1) + (i-1)*ny;
          rxm = (cMap(i,j) + cMap(i-1,j))/2.0;
           rxp = (cMap(i,j) + cMap(i+1,j))/2.0;
          ryp = (cMap(i,j) + cMap(i,j+1))/2.0;
           G(n,n) = -(rxm + rxp + ryp);
           G(n,nxm) = rxm;
           G(n,nxp) = rxp;
           G(n,nyp) = ryp;
       else % middle node
           nxm = j + (i-2)*ny;
           nxp = j + i*ny;
           nym = (j-1) + (i-1)*ny;
          nyp = (j+1) + (i-1)*ny;
           rxm = (cMap(i,j) + cMap(i-1,j))/2.0;
           rxp = (cMap(i,j) + cMap(i+1,j))/2.0;
           rym = (cMap(i,j) + cMap(i,j-1))/2.0;
           ryp = (cMap(i,j) + cMap(i,j+1))/2.0;
           % middle nodes in G, based on the sum of four neighbour
cells
           G(n,n) = -(rxm + rxp + rym + ryp);
           G(n,nxm) = rxm;
           G(n,nxp) = rxp;
           G(n,nym) = rym;
           G(n,nyp) = ryp;
```

% only three resistors:

```
end
end
V = G \backslash F;
Vmap = zeros(nx,ny); % initialize matrix
n = 0; % clear/reset node index n
for i = 1:nx
    for j = 1:ny
        n = j + (i-1)*ny;
        Vmap(i,j) = V(n);
    end
end
Ex = [];
Ey = [];
for i = 1:nx
    for j = 1:ny
        % Calculate Ex
        if i == 1
            Ex(i,j) = Vmap(i+1,j) - Vmap(i,j);
        elseif i == nx
            Ex(i,j) = Vmap(i,j) - Vmap(i-1,j);
        else
            Ex(i,j) = (Vmap(i+1,j) - Vmap(i-1,j)) / 2.0;
        end
        % Calculate Ey
        if j == 1
            Ey(i,j) = Vmap(i,j+1) - Vmap(i,j);
        elseif j == ny
            Ey(i,j) = Vmap(i,j) - Vmap(i,j-1);
        else
            Ey(i,j) = (Vmap(i,j+1) - Vmap(i,j-1)) / 2.0;
        end
    end
end
Ex = -Ex;
Ey = -Ey;
Exy = sqrt(Ex.^2 + Ey.^2);
Jx = cMap.*Ex;
Jy = cMap.*Ey;
Jxy = sqrt(Jx.^2 + Jy.^2);
Current = mean(Jxy.*(regL*regW*10^(13)), 'all');
```

end

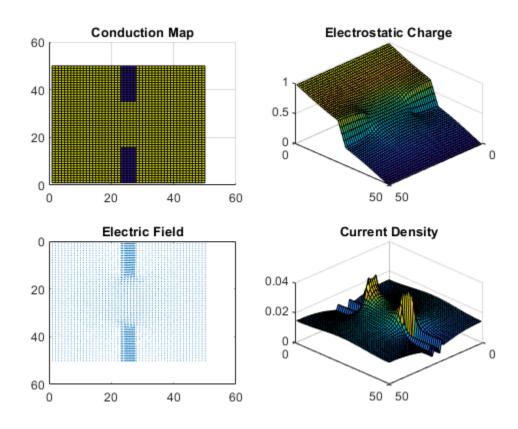
```
figure(7)
subplot(2,2,1); surf(cMap')
title('Conduction Map')
view(2) % adjust camera angle for better view

subplot(2,2,2); surf(Vmap)
title('Electrostatic Charge')
view(135,45) % adjust camera angle for better view

subplot(2,2,3); quiver(Ey,Ex)
title('Electric Field')
view(90,90) % adjust camera angle for 2D view

subplot(2,2,4); surf(Jxy')
title('Current Density')
view(135,45) % adjust camera angle for better view

xPos = regL.*rand(1,numElec); % set random initial x position
yPos = regW.*rand(1,numElec); % set random initial y position
```



Before moving forward, we must ensure all initial positions lie outisde the boxes.

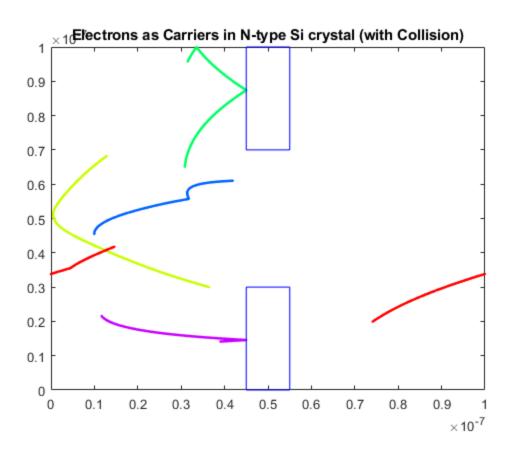
```
for i = 1:numElec
    while ((xPos(i)>=(boxLeft*regL)) && (xPos(i)<=(boxRight*regL))) &&
    (((yPos(i)>=(boxBottom*regW)) || (yPos(i)<=(boxTop*regW))))
        xPos(i) = regL.*rand; % set random initial x position
        yPos(i) = regW.*rand; % set random initial y position</pre>
```

```
end
% velocities will also be assigned randomly according to the
% Maxwell-Boltzmann distribution with an average of the speeds being
 the
% thermal velocity.
xVel = sqrt(3*kb * T/m_n)*randn(1,numElec);
yVel = sqrt(3*kb * T/m_n)*randn(1,numElec);
[Xm,Ym] = meshgrid(L,W);
% we also need to determine the probability of an electron scattering.
% is given by the function: [P_{scat}] = 1 - e^{-dt} \times [mn]
Pscat = 1 - exp(-dt/t_mn);
for t = 1:numTimeStep
    figure(8)
    for n = 1:numDispElec
        plot(xPos(n), yPos(n),'.','color',Cols(n,:))
    end
    title('Electrons as Carriers in N-type Si crystal (with
 Collision)')
    axis([0 regL 0 regW])
    hold on
    makeBox(boxLeft,boxRight,1,boxBottom,reqL,reqW); % top box
    makeBox(boxLeft,boxRight,boxTop,0,regL,regW); % bottom box
    % save old x and y positions
    xPrev = xPos;
    yPrev = yPos;
    randNum = rand(1, numElec); % generate a random number for each
 electron
    scatter = randNum < Pscat; % determine if electron scatters</pre>
    xVel(scatter) = sqrt(3*kb * T/m_n)*randn;
    yVel(scatter) = sqrt(3*kb * T/m n)*randn;
    % use linear interpolation to determine E-field at each electron
 postion
    Exp = interp2(Xm,Ym,Ex,xPos,yPos);
    Eyp = interp2(Xm,Ym,Ey,xPos,yPos);
    % calculate force on each electron
    Fx = q*Exp*10^9;
    Fy = q*Eyp*10^9;
    accelX = (Fx./m_n); % acceleration
    accelY = (Fy./m_n);
```

end

```
% determine new X and Y velocities
   xVel = dt.*accelX + xVel;
   yVel = dt.*accelY + yVel;
   newXPos = xPos + xVel*dt;
   newYPos = yPos + yVel*dt;
   if Btype == 's' % specular boxes, just bounce
       for i = 1:numElec
           if ((newXPos(i)>=(boxLeft*regL)) &&
(newXPos(i)<=(boxRight*regL))) && (((newYPos(i)>=(boxBottom*regW)) | |
(newYPos(i) <= (boxTop*reqW))))</pre>
               if (xPrev(i) <= boxLeft*regL) || (xPrev(i) >=
boxRight*reqL )
                   xVel(i) = -xVel(i);
               elseif (yPrev(i) <= boxBottom*regW) || (yPrev(i) >=
boxTop*regW)
                   yVel(i) = -yVel(i);
               end
           end
       end
   elseif Btype == 'd' % diffusive boxes, re-thermalize
       for i = 1:numElec
           if ((newXPos(i)>=(boxLeft*regL)) &&
(newXPos(i)<=(boxRight*regL))) && (((newYPos(i)>=(boxBottom*regW)) | |
(newYPos(i)<=(boxTop*regW))))</pre>
               if (xPrev(i) <= boxLeft*reqL) || (xPrev(i) >=
boxRight*reqL )
                   xVel(i) = -xVel(i);
                   yVel(i) = sqrt(3*kb * T/m_n)*randn;
               elseif (yPrev(i) <= boxBottom*regW) || (yPrev(i) >=
boxTop*reqW)
                   xVel(i) = sqrt(3*kb * T/m_n)*randn;
                    yVel(i) = -yVel(i);
               end
           end
       end
   end
   crossRight = newXPos >= regL;
   crossLeft = newXPos <= 0;</pre>
   xPos = xPos + xVel*dt;
   xPos(crossRight) = 0;
   xPos(crossLeft) = reqL;
   crossTop = newYPos > reqW;
   crossBottom = newYPos < 0;</pre>
   yVel(crossTop) = -yVel(crossTop);
   yVel(crossBottom) = -yVel(crossBottom);
   yPos = yPos + yVel*dt;
```

end



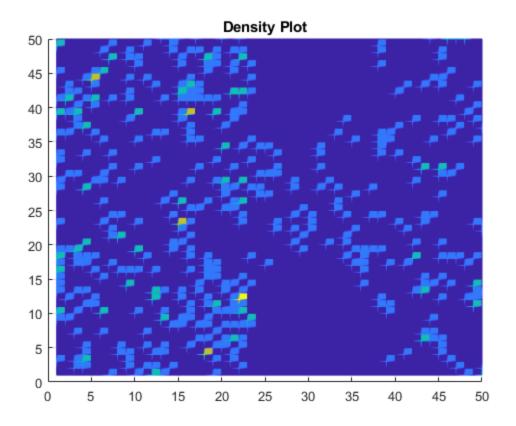
Density Plot

segments the

After the completion of the simulation, we can take the final positions of the electrons and create a density plot. To do this, we divide the region into a meshgrid, loop through each differential area and count the number of electrons in that area creating a matrix of the number of electrons located in each segment of the region. This matrix can be plotted as a surface to help us visualize the electron density of the area.

- \$ xPos and yPos now hold the final x and y positions of the electrons \$ respectively. nx and ny (declared in main) are the number of
- $\mbox{\ensuremath{\upsigma}}\ x$ and y directions will be divided into thus the region will be divided
- % into nx*ny smaller areas. We can divide the electrons x and y positions
- $\mbox{\ensuremath{\upsigma}}$ by the length and width and multiply by nx and ny respectively to obtain
- % the index in which each electron resides in (these will have to be % rounded up such that we are left with only whole integer values)
- xi = ceil(xPos/regL*nx); % x index
 yi = ceil(yPos/regW*ny); % y index

```
% loop through each smaller area and count the number of electrons
present
for i = 1:nx
    for j = 1:ny
        match = (xi==i) & (yi==j); % search for all electrons at the
 current i,j index
        % match will have a 1 for every electron located at current
 index,
        % taking the sum gives the total number of electrons located
 at
        % this cell in the meshgrid
        sum_e = sum(match);
        densityPlot(i,j) = sum_e; % save this sum into a matrix to be
mapped out
    end
end
densityPlot = densityPlot';
figure(9)
surf(densityPlot,'EdgeColor','interp')
view(2)
title('Density Plot')
```



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